

IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application.

1-4. (Canceled).

5. (Previously Presented) A light emitting device having an organic electroluminescence element, the organic electroluminescence element comprising:

an anode and a cathode;

an organic luminescent layer formed between the anode and the cathode;

a hole transport layer formed between the anode and the organic luminescent layer; and

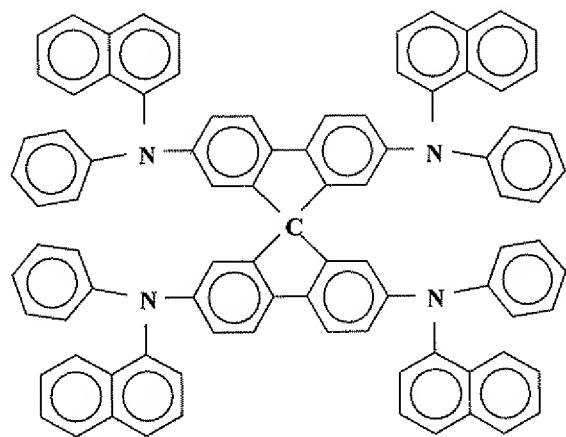
a hole blocking layer formed between the cathode and the organic luminescent layer,

wherein the organic luminescent layer is capable of converting triplet excitation energy into light to be emitted,

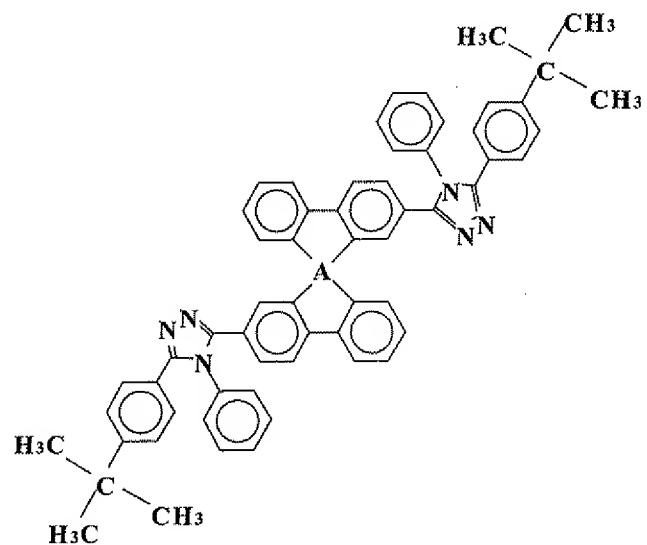
wherein the organic luminescent layer includes a host material and a luminescent material,

wherein the luminescent material comprises a metal complex,

wherein the hole transport layer comprises a material expressed by the following formula

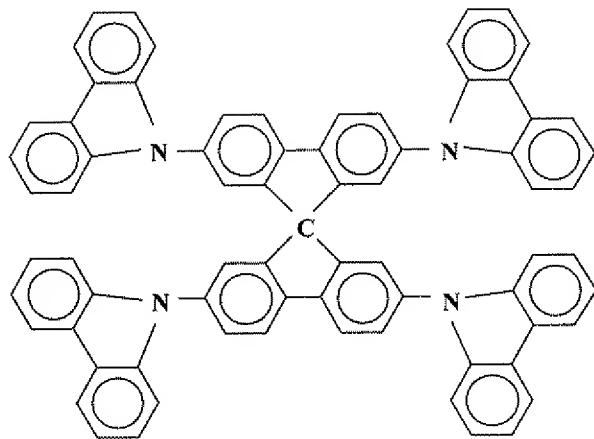


wherein the hole blocking layer comprises a material expressed by the following formula



wherein “A” indicates carbon, and

wherein the host material comprises a material expressed by the following formula

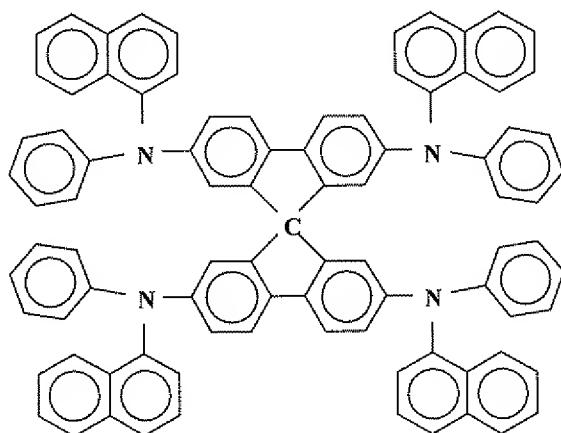


6. (Original) An electronic appliance comprising said light emitting device according to claim 5, wherein said electronic appliance is selected from the group consisting of an organic electroluminescence display, a video camera, a digital camera, a portable computer, a personal computer, a mobile telephone, and an acoustic equipment.

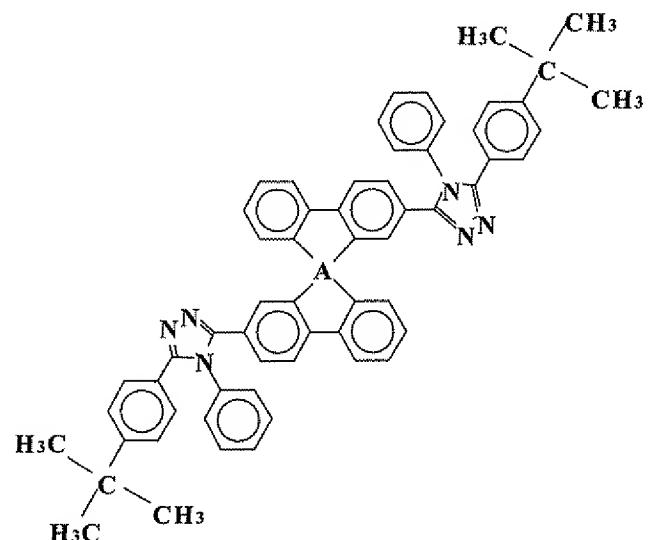
7-8. (Canceled)

9. (Previously Presented) A light emitting device having an organic electroluminescence element, the organic electroluminescence element comprising:
an anode and a cathode;
an organic luminescent layer formed between the anode and the cathode;
a hole transport layer formed between the anode and the organic luminescent layer; and
a hole blocking layer formed between the cathode and the organic luminescent layer,
wherein the organic luminescent layer is capable of converting triplet excitation energy into light to be emitted,

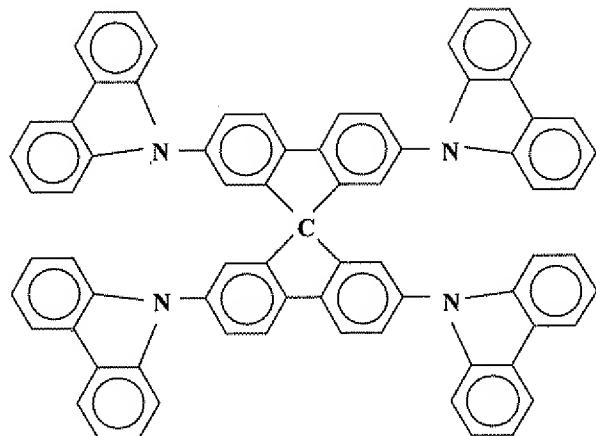
wherein the organic luminescent layer includes a host material and a luminescent material,
wherein the luminescent material comprises a metal complex,
wherein the hole transport layer comprises a material expressed by the following formula



wherein the hole blocking layer comprises a material expressed by the following formula,



wherein “A” indicates silicon, and
wherein the host material comprises a material expressed by the following formula



10. (Original) An electronic appliance comprising said light emitting device according to claim 9, wherein said electronic appliance is selected from the group consisting of an organic electroluminescence display, a video camera, a digital camera, a portable computer, a personal computer, a mobile telephone, and an acoustic equipment.

11-14. (Canceled)

15. (Previously Presented) A light emitting device according to claim 5, wherein said metal complex is selected from the group consisting of 2,3,7,8,12,13,17,18-octaethyl-21H,23H-porphyrin -platinum (PtOEP) and tris(2-phenylpyridine)iridium (Ir(ppy)3).

16. (Canceled)

17. (Previously Presented) A light emitting device according to claim 9, wherein said metal complex is selected from the group consisting of 2,3,7,8,12,13,17,18-octaethyl-21H,23H-porphyrin -platinum (PtOEP) and tris(2-phenylpyridine)iridium (Ir(ppy)3).

18. (Canceled)

19. (Previously Presented) A light emitting device according to claim 5, wherein the light emitting device is an active light emitting device.

20. (Previously Presented) A light emitting device according to claim 19, wherein a thin film transistor is formed over a substrate in the active light emitting device.

21. (Previously Presented) A light emitting device according to claim 5, further comprising an electron transporting layer over the hole blocking layer.

22. (Previously Presented) A light emitting device according to claim 5, further comprising a polarization plate in a display screen of the light emitting device.

23-26. (Canceled)

27. (Previously Presented) A light emitting device according to claim 9, wherein the light emitting device is an active light emitting device.

28. (Previously Presented) A light emitting device according to claim 27, wherein a thin film transistor is formed over a substrate in the active light emitting device.

29. (Previously Presented) A light emitting device according to claim 9, further comprising an electron transporting layer over the hole blocking layer.

30. (Previously Presented) A light emitting device according to claim 9, further comprising a polarization plate in a display screen of the light emitting device.

31-34. (Canceled)